

### 3 A LOW Vf Schottky Barrier Rectifier

#### DESCRIPTION

This UPS340e3 in the Powermite3<sup>®</sup> package is a high efficiency Schottky rectifier that is also RoHS compliant offering high current/power capabilities previously found only in much larger packages. They are ideal for SMD applications that operate at high frequencies. In addition to its size advantages, the Powermite3<sup>®</sup> package includes a full metallic bottom that eliminates the possibility of solder flux entrapment during assembly and a unique locking tab act as an efficient heat path to the heat-sink mounting. Its innovative design makes this device ideal for use with automatic insertion equipment.

#### KEY FEATURES

- Very low thermal resistance package
- RoHS Compliant with e3 suffix part number
- Guard-ring-die construction for transient protection
- Efficient heat path with Integral locking bottom metal tab
- Low forward voltage
- Full metallic bottom eliminates flux entrapment
  - Compatible with automatic insertion
- Low profile-maximum height of 1mm

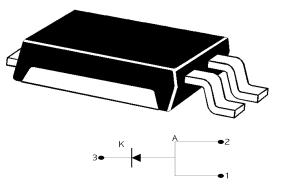
#### IMPORTANT: For the most current data, consult *MICROSEM* is website: http://www.microsemi.com

ABSOLUTE MAXIMUM RATINGS AT 25° C (UNLESS OTHERWISE SPECIFIED)					
Rating	Symbol	Value	Unit		
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	40	v		
RMS Reverse Voltage	V <sub>R (RMS)</sub>	28	V		
Average Rectified Output Current	Ι <sub>ο</sub>	3	А		
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine wave Superimposed on Rated Load@ T <sub>c</sub> =90 °C	I <sub>FSM</sub>	50	А		
Storage Temperature	$T_{STG}$	-55 to +150	°C		
Junction Temperature	TJ	-55 to +125	°C		

#### THERMAL CHARACTERISTICS

Thermal Resistance				
Junction-to-case (bottom)	R <sub>0JC</sub>	3.2	°C/ Watt	
Junction to ambient (1)	R <sub>0JA</sub>	65	°C/ Watt	
(1) When mounted on FR-4 PC board using 2 oz copper with recommended minimum foot print				

#### Powermite 3<sup>™</sup>



APPLICATIONS/BENEFITS						
<ul> <li>Switching and Regulating Power Supplies.</li> <li>Silicon Schottky (hot carrier) rectifier for minimal reverse voltage recovery</li> <li>Elimination of reverse-recovery oscillations to reduce need for EMI filtering</li> <li>Charge Pump Circuits</li> <li>Reduces reverse recovery loss with low I<sub>RM</sub></li> <li>Small foot print</li> </ul>						
190 X 270 mils (1:1 Actual size) See mounting pad details on pg 3						
MECHANICAL & PACKAGING						
<ul> <li>CASE: Void-free transfer molded thermosetting epoxy compound meeting UL94V-0</li> </ul>						
<ul> <li>FINISH: Annealed matte-Tin plating over</li> </ul>						

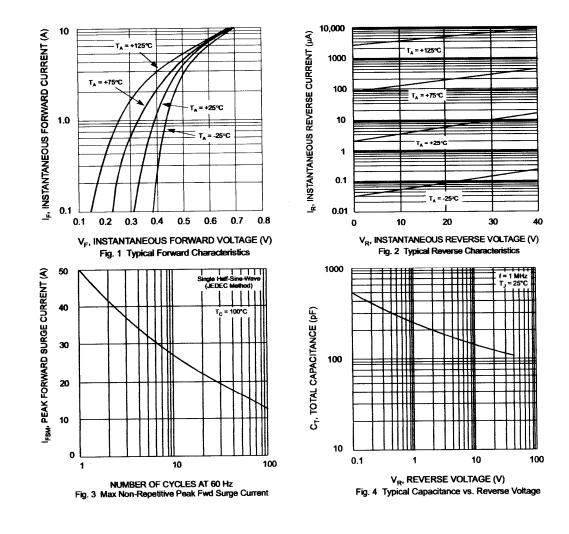
- FINISH: Annealed matte-Tin plating over copper and readily solderable per MIL-STD-750 method 2026 (consult factory for Tin-Lead plating)
- POLARITY: See figure (left)
- MARKING: S340•
- WEIGHT: 0.072 gram (approx.)
- Package dimension on last page
- Tape & Reel option: 16 mm tape per Standard EIA-481-B, 5000 on 13" reel



### 3 A LOW Vf Schottky Barrier Rectifier

ELECTRICAL PARAMETERS @ 25°C (unless otherwise specified)						
Parameter	Symbol	Conditions	Min	Тур.	Max	Units
Forward Voltage (Note 1)		$I_F = 3 A$ , $T_j = 25 °C$		0.46	0.50	
	V <sub>F</sub>	$I_F = 3 A$ , $T_j = 125 °C$ $I_F = 6 A$ , $T_j = 25 °C$		0.40 0.57	0.44 0.61	V
Reverse Break Down Voltage (Note 1)	V <sub>BR</sub>	$I_F = 6 \text{ A}, T_i = 125 \text{ °C}$ $I_R = 0.5 \text{ mA}$	40	0.54	0.58	V
Reverse Current (Note1)	I <sub>R</sub>	V <sub>R</sub> = 40V, T <sub>j</sub> = 25 °C V <sub>R</sub> = 40V, T <sub>j</sub> =100 °C		15 10	500 20	uA mA
Capacitance	CT	V <sub>R</sub> = 4 V; f = 1 MH <sub>Z</sub>		180		pF

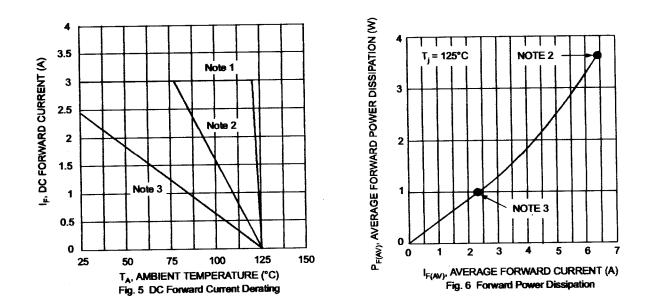
Note: 1 Short duration test pulse used to minimize self - heating effect.



UPS340e3

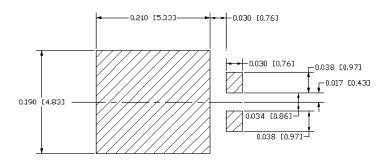


# 3 A LOW Vf Schottky Barrier Rectifier



- Notes: 1.  $T_A = T_{SOLDERING POINT}$ ,  $R_{\Theta JS} = 3.2^{\circ} \text{ C/W}$   $R_{\Theta SA} = 0^{\circ} \text{ C/W}$ . 2. Device mounted on GETEK substrate, 2" x 2", 2 oz. copper, double-sided, cathode pad dimensions 0.75" x 1.0", anode pad dimensions 0.25" x 1.0". R<sub>OJA</sub> in range of 20-40° C/W.
  - 3. Device mounted on FRA-4 substrate, 2" x 2", 2 oz. copper, single-sided, pad layout  $R_{\Theta JA}$  in range of 65° C/W. See mounting pad below.

#### **MOUNTING PAD DIMENSIONS (inches)**

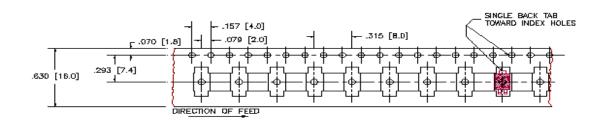


UPS340e3

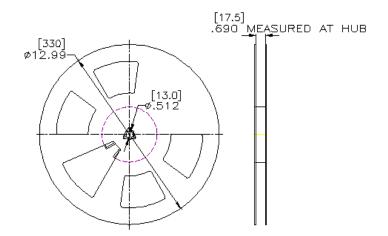


## 3 A LOW Vf Schottky Barrier Rectifier

TAPE & REEL



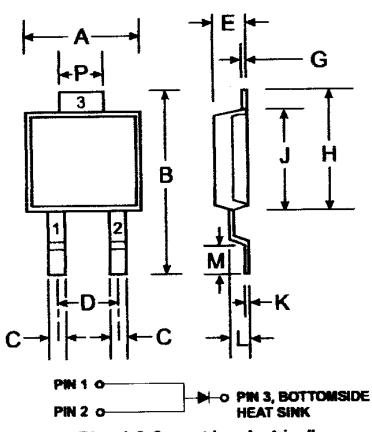
13 INCH REEL

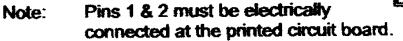




### 3 A LOW Vf Schottky Barrier Rectifier

#### PACKAGE DIMENSIONS





POWERMITE®3				
Dim	Min Max			
•	4.03	4.09		
B	6.40	6.61		
С	.889 NOM			
D	1.83 NOM			
E	1.10	1.14		
G	.178 NOM			
H	5.01 5.17			
J	4.37	4.43		
К	.178 NOM			
L	.71	.77		
M	.36	.46		
Р	1.73	1.83		
All Dimensions in mm				



# 3 A LOW Vf Schottky Barrier Rectifier

•	NOTES:	www. <i>Microsemi</i> .com
	NOTES	UPS340e3